

QUADRUPLE 2-INPUT NAND GATES WITH SCHMITT TRIGGER INPUTS

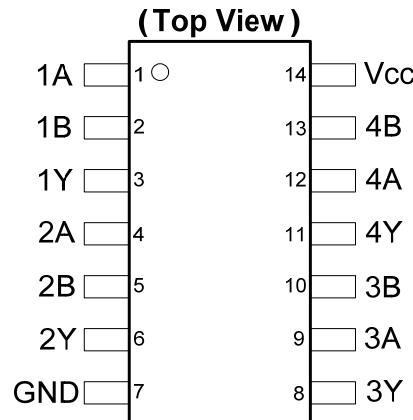
Description

The 74LV132A provides four independent 2-input NAND gates with standard push-pull outputs. Each input is a Schmitt Trigger device with a significant amount of hysteresis suiting the device for noisy environments. The device is designed for operation with a power supply range of 2.0V to 5.5V.

The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

The gates perform the Boolean function:

$$Y = \overline{A} \bullet \overline{B} \text{ or } Y = \overline{A} + \overline{B}$$

Pin Assignments

SO-14 / TSSOP-14

Features

- Wide Supply Voltage Range from 2.0V to 5.5V
- Sinks or sources 12mA at $V_{CC} = 4.5V$
- CMOS low power consumption
- I_{OFF} Supports Partial -Power Down Operation
- Inputs or Outputs accept up to 5.5V
- Inputs can be driven by 3.3V or 5V allowing for voltage translation applications.
- Schmitt Trigger Action at All Inputs
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)**

Applications

- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
 - PCs, networking, notebooks, ultrabooks, netbooks
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box

Notes:

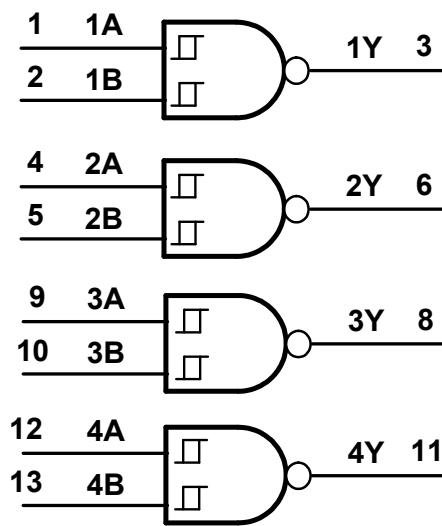
- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

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Pin Descriptions

Pin Number	Pin Name	Description
1	1A	Data Input
2	1B	Data Input
3	1Y	Data Output
4	2A	Data Input
5	2B	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	3B	Data Input
11	4Y	Data Output
12	4A	Data Input
13	4B	Data Input
14	Vcc	Supply Voltage

Logic Diagram



Function Table

Inputs		Output
A	B	Y
H	H	L
L	X	H
X	L	H

Absolute Maximum Ratings (Note 4)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 7.0	V
V _I	Input Voltage Range note 4	-0.5 to 7.0	V
I _{IK}	Input Clamp Current V _I < 0V	-20	mA
I _{OK}	Output Clamp Current V _O < -0V	-50	mA
I _O	Continuous Output Current - 0.5V < V _O V _{CC} + 0.5V	+/- 25	mA
I _{CC}	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
T _J	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommended values.

Recommended Operating Conditions (Note 5)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply Voltage	—	2.0	5.5	V
V_I	Input Voltage	—	0	5.5	V
V_O	Output Voltage	—	0	V_{CC}	V
I_{OH}	High-Level Output Current	2.0V	—	-50	mA
		2.3V to 2.7V	—	-2	μA
		3.0V to 3.6V	—	-6	mA
		4.5V to 5.5V	—	-12	mA
I_{OL}	Low-Level Output Current	2.0V	—	50	μA
		2.3V to 2.7V	—	2	mA
		3.0V to 3.6V	—	6	mA
		4.5V to 5.5V	—	12	mA
T_A	Operating Free-Air Temperature	—	-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics

Symbol	Parameter	Test Conditions	V_{CC}	$T_A = -40$ to $+85^\circ C$		$T_A = -40$ to $+125^\circ C$		Unit
				Min	Max	Min	Max	
V_{T+}	Positive Going Threshold	—	2.5 V	1	1.75	1	1.75	V
		—	3.3 V	1.31	2.31	1.31	2.31	
		—	5.0 V	1.95	3.5	1.95	3.5	
V_{T-}	Negative Going Threshold	—	2.5 V	0.75	1.5	0.75	1.5	—
		—	3.3 V	0.99	2.07	0.99	2.07	
		—	5.0 V	1.5	3.05	1.5	3.05	
V_H	Hysteresis ($V_{T+} - V_{T-}$)	—	2.5 V	0.25	1	0.25	1	V
		—	3.3 V	0.33	1.32	0.33	1.32	
		—	5.0 V	0.5	2	0.5	2	
V_{OH}	High-Level Output Voltage	$I_{OH} = -50\mu A$	2.0V to 5.5V	$V_{CC}-0.1$	—	$V_{CC}-0.1$	—	V
		$I_{OH} = -2mA$	2.3V	2.0	—	2.0	—	
		$I_{OH} = -6mA$	3.0V	2.48	—	2.48	—	
		$I_{OH} = -12mA$	4.5V	3.8	—	3.8	—	
V_{OL}	Low-Level Output Voltage	$I_{OL} = 50\mu A$	2.0V to 5.5V	—	0.1	—	0.1	V
		$I_{OL} = 2mA$	2.3V	—	0.4	—	0.4	
		$I_{OL} = 6mA$	3.0V	—	0.44	—	0.44	
		$I_{OL} = 12mA$	4.5V	—	0.55	—	0.55	
I_{OFF}	Power Down Leakage Current	V_I or $V_O = 0$ to 5.5V	0V	—	5	—	5	μA
I_I	Input Current	$V_I = GND$ or 5.5V	0 to 5.5V	—	± 1	—	± 1	μA
I_{CC}	Supply Current	$V_I = GND$ or V_{CC} $I_O=0$	5.5V	—	20	—	20	μA

Switching Characteristics

Symbol	Parameter	Test Conditions	V _{CC}	T _A = +25°C			-40 to +85°C		-40 to +125°C		Unit	
				Min	Typ.	Max	Min	Max	Min	Max		
t _{PD}	Propagation Delay A _N to Y _N	Figure 1 C _L =15pF	2.5V ± 0.2V	—	7.9	16.5	1	18.5	1	18.5	ns	
			3.3V ± 0.3V	—	5.6	11.9	1	14	1	14		
			5.0V ± 0.5V	—	3.9	7.7	1	9	1	9		
	Figure 1 C _L =50 pF		2.5V ± 0.2V	—	10.8	20.2	1	23	1	23	ns	
			3.3V ± 0.3V	—	7.6	15.4	1	17.5	1	17.5		
			5.0V ± 0.5V	—	5.3	9.7	1	11	1	11		

Operating Characteristics

 T_A = +25°C

Parameter		Test Conditions	V _{CC}	TYP	Unit
C _{pd}	Power Dissipation Capacitance per Gate	F= 10 MHz C _L =50pF	3.3V	7.5	pF
			5.0V	11.2	

Noise Characteristics

 V_{CC} = 3V, C_L=50pF, T_A = +25°C

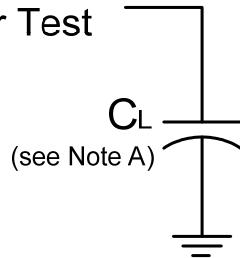
Symbol	Parameter	Min	Typ.	Max	Unit
V _{OL(p)}	Quiet output, maximum dynamic V _{OL}	—	0.2	0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}	—	-0.1	-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}	—	3.1	—	V
V _{IH(D)}	High Level dynamic input voltage	2.31	—	—	V
V _{IL(D)}	Low Level dynamic input voltage	—	—	0.99	V

Package Characteristics

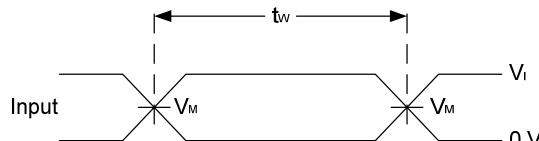
Symbol	Parameter	Test Conditions	V _{CC}	Min	Typ.	Max	Unit
C _i	Input Capacitance	V _i = V _{CC} – or GND	2.0 to 5.5V	—	3.3	10	pF

Parameter Measurement Information

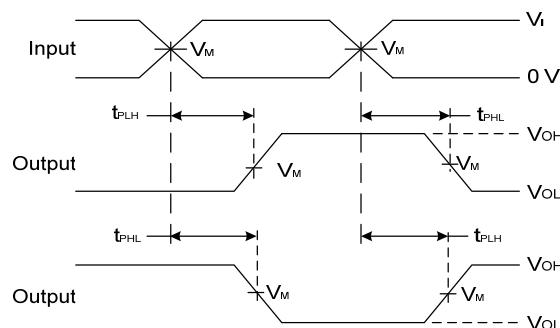
From Output Under Test



V_{CC}	Inputs		V_M	C_L
	V_I	t_r / t_f		
2.0V to 5.5V	V_{CC}	<3ns	$V_{CC} / 2$	15pF or 50pF



**Voltage Waveform
Pulse Duration**



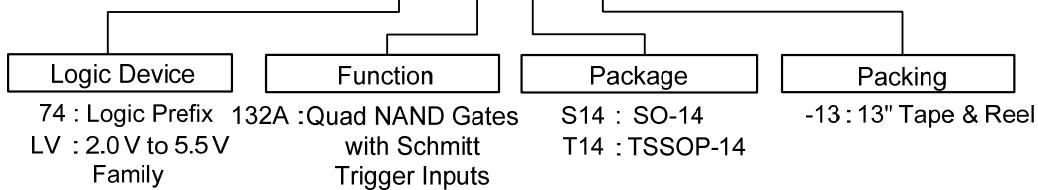
**Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs**

- Notes:
- Includes test lead and test apparatus capacitance.
 - All pulses are supplied at pulse repetition rate $\leq 10\text{MHz}$
 - Inputs are measured separately one transition per measurement
 - t_{PLH} and t_{PHL} are the same as t_{PD}

Figure 1. Load Circuit and Voltage Waveforms

Ordering Information

74 LV 132AXXX - 13

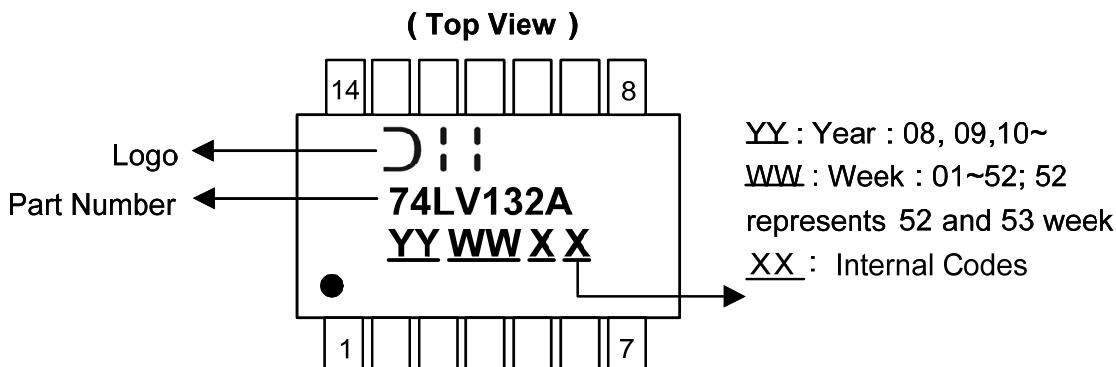


Device	Package Code	Packaging (Note 6)	13" Tape and Reel	
			Quantity	Part Number Suffix
74LV132AS14-13	S14	SO-14	2500/Tape & Reel	-13
74LV132AT14-13	T14	TSSOP-14	2500/Tape & Reel	-13

Note: 6. The taping orientation and tape details can be found at <http://www.diodes.com/datasheets/ap02007.pdf>

Marking Information

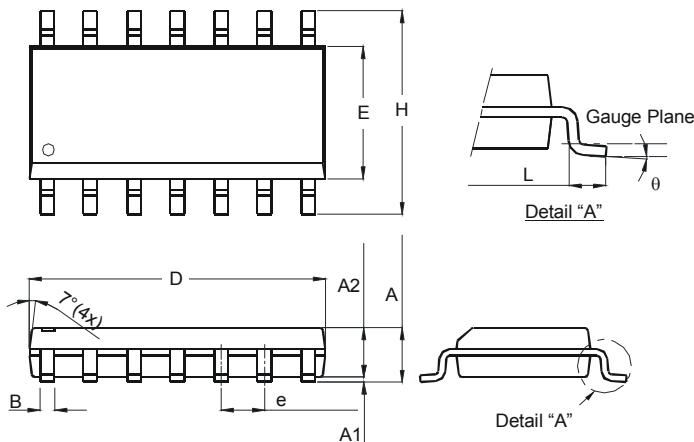
(1) SO14, TSSOP14



Part Number	Package
74LV132AS14	SO-14
74LV132AT14	TSSOP-14

Package Outline Dimensions (All Dimensions in mm)

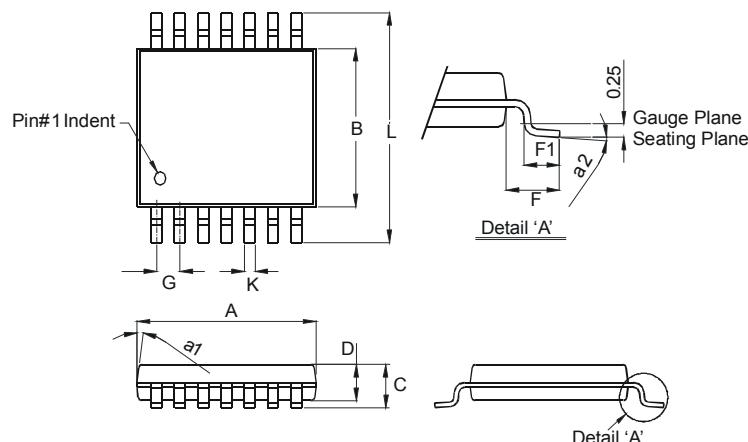
Package Type: SO-14



SO-14		
Dim	Min	Max
A	1.47	1.73
A1	0.10	0.25
A2	1.45 Typ	
B	0.33	0.51
D	8.53	8.74
E	3.80	3.99
e	1.27 Typ	
H	5.80	6.20
L	0.38	1.27
θ	0°	8°

All Dimensions in mm

Package Type: TSSOP-14

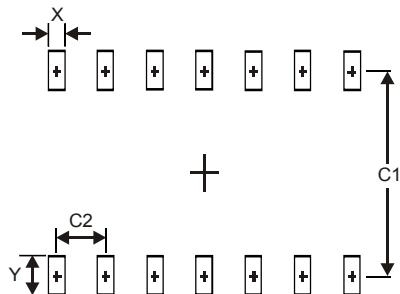


TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
A	4.9	5.10
B	4.30	4.50
C	—	1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	

All Dimensions in mm

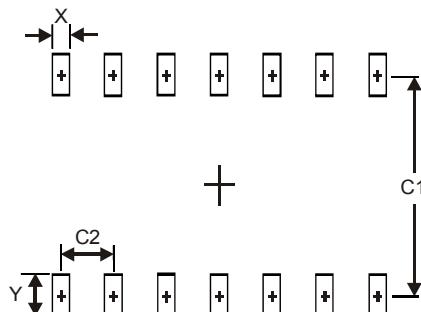
Suggested Pad Layout

Package Type: SO-14



Dimensions	Value (in mm)
X	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
X	0.45
Y	1.45
C1	5.9
C2	0.65

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